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# REEDFAX US005999446A

# **United States Patent**

Harari et al.

[54] MULTI-STATE FLASH EEPROM SYSTEM WITH SELECTIVE MULTI-SECTOR ERASE

2154415463

[75] Inventors: Eliyahou Harari, Los Gatos; Robert D. Norman, San Jose; Sanjay Mehrotra, Milpitas, all of Calif.

[73] Assignce: SanDisk Corporation, Sunnyvale, Calif.

[21] Appl. No.: 08/999,498

[22] Filed: Dec. 29, 1997

# Related U.S. Application Data

Continuation of application No. 08/407,916, Mar. 21, 1995, Pat. No. 5,719,808, which is a continuation of application No. 07/963,851, Oct. 20, 1992, Pat. No. 5,418,752, which is a division of application No. 07/337.666, Apr. 13, 1989, abandoned. Int. Cl.6 ..... G11C 16/04 [51] [52] 365/185.11; 365/185.3; 365/185.33; 365/185.09 

> [56] References Cited

### U.S. PATENT DOCUMENTS

365/185.3, 185.33, 185.03, 185.09

_			
	3,895,360	7/1975	Cricchi et al
١	3,898,632	8/1975	Spencer, Jr 365/184
ļ	3,906,455	9/1975	Houston et al 711/108
l	3,914,750	10/1975	Hadden, Jr 365/184
l	4,005,389	1/1977	Penzel 711/173
ı	4,044,339	8/1977	Berg 365/240
ľ	4,058,799	11/1977	George et al 365/14
	4,064,405		Cricchi et al
	4,090,258		Cricchi 365/184
	4,099,069	7/1978	Cricchi et al 365/218

(List continued on next page.)

# FOREIGN PATENT DOCUMENTS

0283238 9/1988 European Pat. Off. . 0392895 10/1990 European Pat. Off. .

Patent Number: [11]

5,999,446

Date of Patent: [45]

Dec. 7, 1999

4119394 12/1991 Germany 1/1977 Japan . 52-8738 58-86777 5/1983 Japan .

(List continued on next page.)

#### OTHER PUBLICATIONS

J.E. Brewer et al., "Block-Oriented Random Access MNOS Memory," National Computer Conference and Exposition, Chicago, May 6-10, 1974, AFIPS Conference Proceedings, vol. 43, pp. 837-840.

J.E. Brower et al., "Low Cost MNOS BORAM,"Proceedings of IEEE National Aerospace Electronics Conference, NAECON '77, May 17-19, 1977, pp. 624-626.

J.R. Cricchi et al., "Nonvolatile Block-Oriented RAM," IEEE International Solid-State Circuits Conference, Feb. 13-15, 1974, Digest of Technical Papers, pp. 204-205. Raul-Adrian Cemea et al., "A 1Mb Flash EEPROM," 1989 IEEE International Solid-State Circuits Conference.

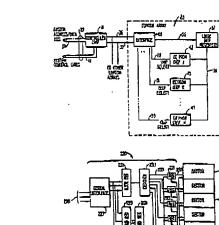
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Primary Examiner-David Nelms Assistant Examiner-Andrew Q. Tran Anorney, Agent, or Firm-Majestic, Parsons, Siebert &

#### **ABSTRACT** [57]

A system of Flash EEprom memory chips with controlling circuits serves as non-volatile memory such as that provided by magnetic disk drives. Improvements include selective multiple sector crase, in which any combinations of Flash sectors may be erased together. Selective sectors among the selected combination may also be de-selected during the erase operation. Another improvement is the ability to remap and replace defective cells with substitute cells. The remapping is performed automatically as soon as a defective cell is detected. When the number of defects in a Flash sector becomes large, the whole sector is remapped. Yet another improvement is the use of a write cache to reduce the number of writes to the Flash EEprom memory, thereby minimizing the stress to the device from undergoing too many write/erase cycling.

## 27 Claims, 5 Drawing Sheets



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